



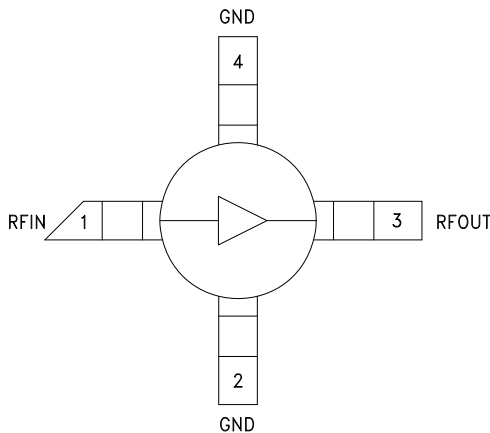
SiGe HBT GAIN BLOCK MMIC AMPLIFIER, DC - 6 GHz

Typical Applications

The HMC474MP86 & HMC474MP86E is an ideal RF/IF gain block for:

- Cellular / PCS / 3G
- Fixed Wireless & WLAN
- CATV, Cable Modem & DBS
- Microwave Radio & Test Equipment

Functional Diagram



Features

- Gain: 15.5 dB
- P1dB Output Power: +8 dBm
- Output IP3: +22 dBm
- Cascadable 50 Ohm I/Os
- Single Supply: +3V to +10V
- Included in the HMC-DK001 Designer's Kit

General Description

The HMC474MP86 & HMC474MP86E are general purpose SiGe Heterojunction Bipolar Transistor (HBT) Gain Block MMIC SMT amplifiers covering DC to 6 GHz. This Micro-P packaged amplifier can be used as a cascadable 50 Ohm RF/IF gain stage with up to +10 dBm output power. The HMC474MP86(E) offer 15.5 dB of gain with a +22 dBm output IP3 at 850 MHz while requiring only 25 mA from a single positive supply. The Darlington feedback pair used results in reduced sensitivity to normal process variations and excellent gain stability over temperature while requiring a minimal number of external bias components.

Electrical Specifications, $V_s = 5V$, $R_{bias} = 110 \text{ Ohm}$, $T_A = +25^\circ \text{ C}$

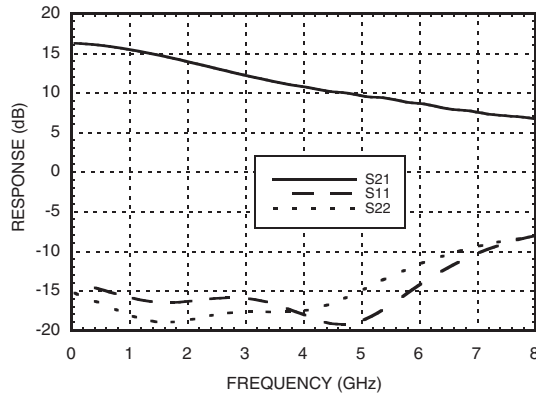
Parameter	Min.	Typ.	Max.	Units
Gain	DC - 1.0 GHz	13	15.5	dB
	1.0 - 2.0 GHz	12	14	dB
	2.0 - 3.0 GHz	10	12	dB
	3.0 - 4.0 GHz	9	11	dB
	4.0 - 5.0 GHz	8	10	dB
	5.0 - 6.0 GHz	7	9	dB
Gain Variation Over Temperature	DC - 6 GHz	0.01	0.015	dB/ °C
Input Return Loss	DC - 1.0 GHz	15		dB
	1.0 - 4.0 GHz	16		dB
	4.0 - 5.0 GHz	19		dB
	5.0 - 6.0 GHz	16		dB
Output Return Loss	DC - 5 GHz	17		dB
	5.0 - 6.0 GHz	13		dB
Reverse Isolation	DC - 4 GHz	17		dB
Output Power for 1 dB Compression (P1dB)	0.5 - 4.0 GHz	5	8	dBm
	4.0 - 5.0 GHz	4	7	dBm
	5.0 - 6.0 GHz	3	6	dBm
Output Third Order Intercept (IP3) (Pout= 0 dBm per tone, 1 MHz spacing)	0.5 - 4.0 GHz	22		dBm
	4.0 - 5.0 GHz	20		dBm
	5.0 - 6.0 GHz	17		dBm
Noise Figure	DC - 5 GHz	3		dB
	5.0 - 6.0 GHz	3.4		dB
Supply Current (Icq)		25		mA

Note: Data taken with broadband bias tee on device output.

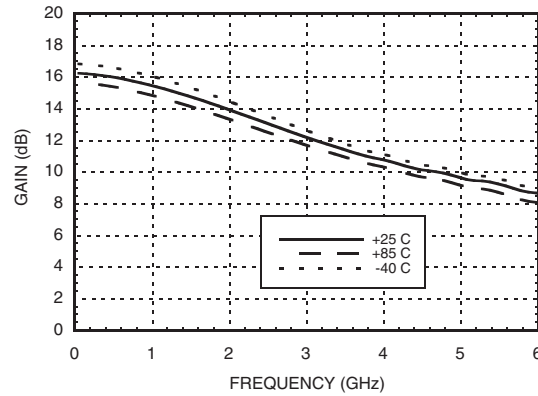
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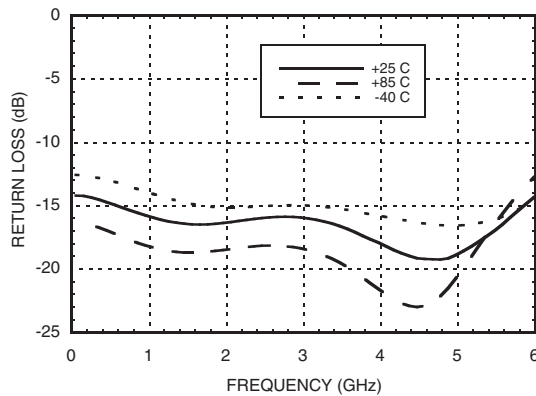
Broadband Gain & Return Loss



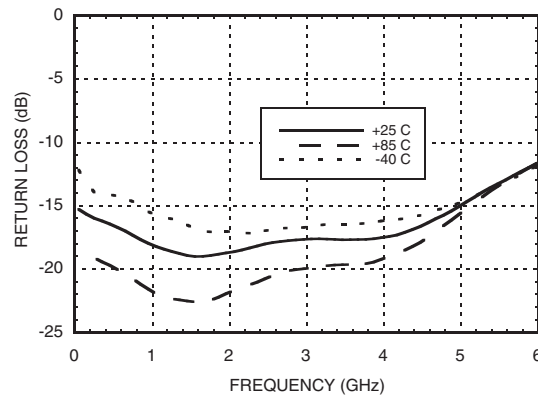
Gain vs. Temperature



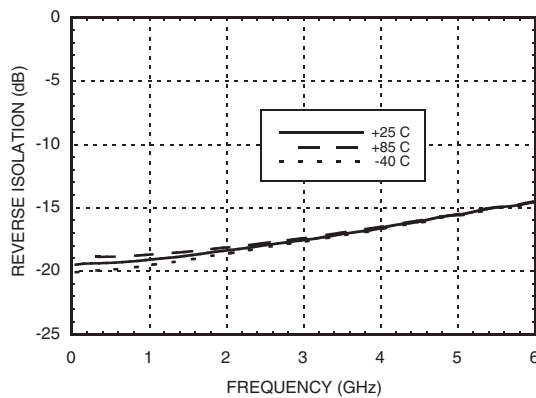
Input Return Loss vs. Temperature



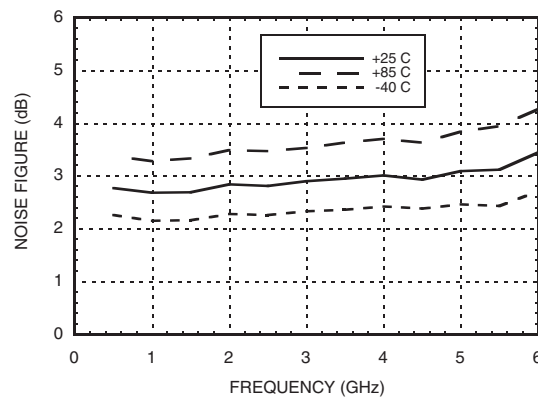
Output Return Loss vs. Temperature



Reverse Isolation vs. Temperature



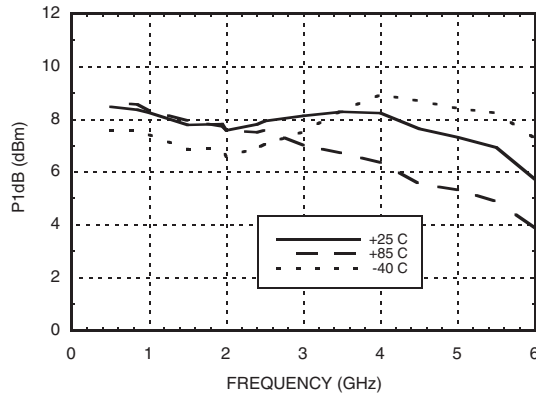
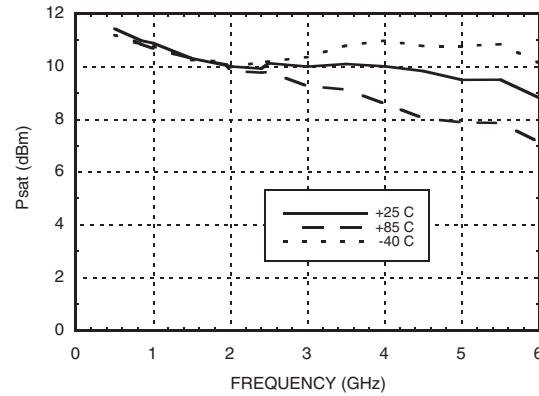
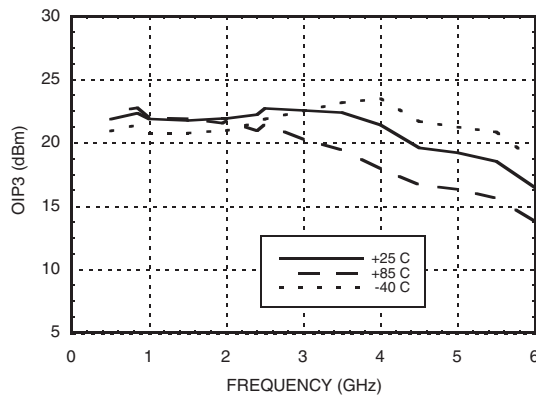
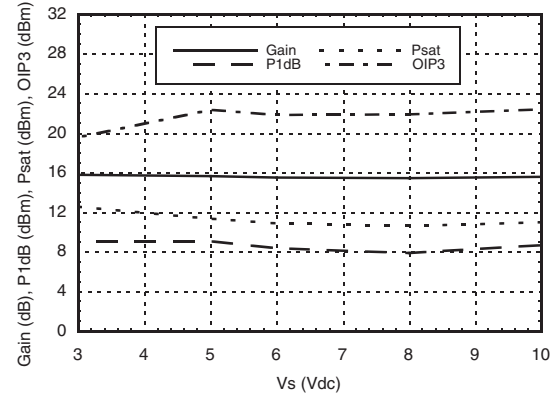
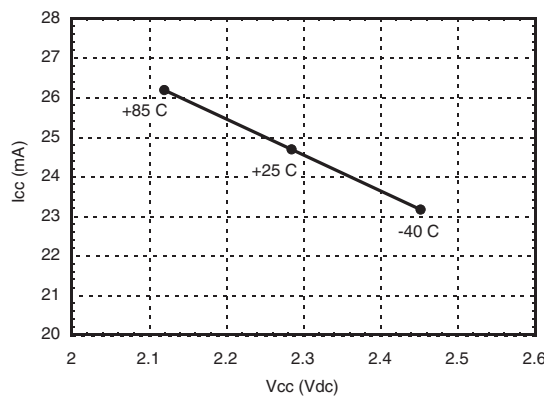
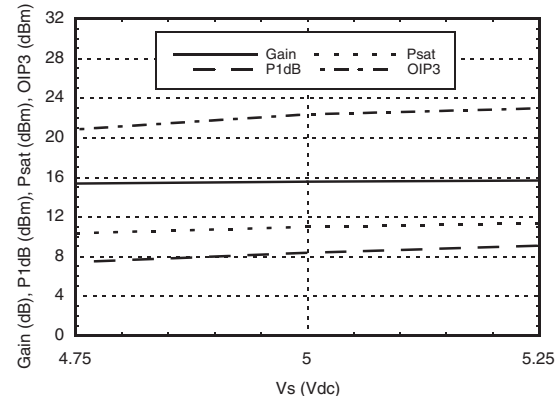
Noise Figure vs. Temperature



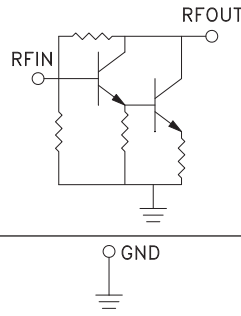


HMC474MP86 / 474MP86E

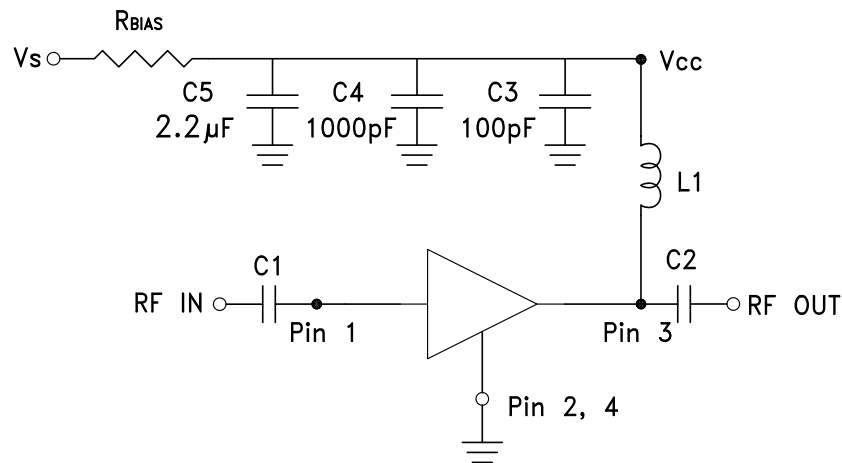
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P1dB vs. Temperature

Psat vs. Temperature

Output IP3 vs. Temperature

**Gain, Power & OIP3 vs. Supply Voltage
for Constant $I_{CC} = 25$ mA @ 850 MHz**

 **I_{CC} vs. V_{CC} Over Temperature for
Fixed $V_S = 5$ V, $R_{BIAS} = 110$ Ohms**

**Gain, Power & OIP3 vs. Supply Voltage
for $R_S = 110$ Ohms @ 850 MHz**


Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	RFIN	This pin is DC coupled. An off chip DC blocking capacitor is required.	
3	RFOUT	RF output and DC Bias (Vcc) for the output stage.	
2, 4	GND	These pins must be connected to RF/DC ground.	

Application Circuit



Recommended Bias Resistor Values for $I_{cc} = 25 \text{ mA}$, $R_{bias} = (V_s - V_{cc}) / I_{cc}$

Supply Voltage (Vs)	3V	5V	6V	8V	10V
RBIAS VALUE	30 Ω	110 Ω	150 Ω	240 Ω	300 Ω
RBIAS POWER RATING	1/8 W	1/8 W	1/4 W	1/2 W	1/2 W

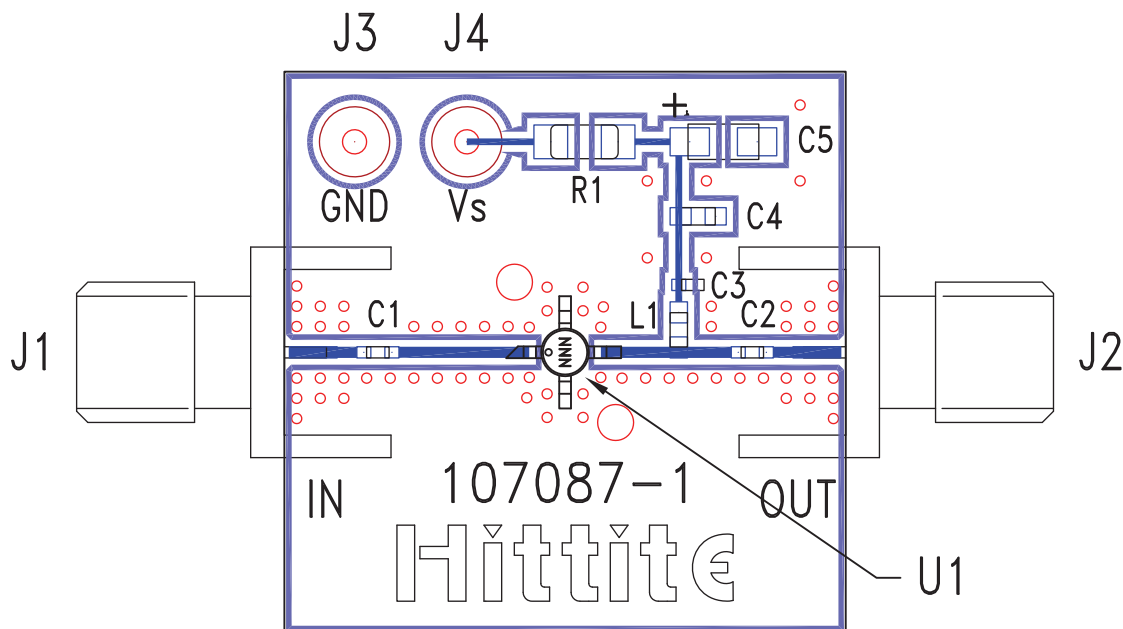
Note:

- External blocking capacitors are required on RFIN and RFOUT.
- RBIAS provides DC bias stability over temperature.

Recommended Component Values for Key Application Frequencies

Component	Frequency (MHz)							
	50	900	1900	2200	2400	3500	5200	5500
L1	270 nH	56 nH	18 nH	18 nH	15 nH	8.2 nH	6.8 nH	3.3 nH
C1, C2	0.01 μF	100 pF	100 pF	100 pF	100 pF	100 pF	100 pF	100 pF

Evaluation PCB



List of Materials for Evaluation PCB 107179 [1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3 - J4	DC Pin
C1, C2	Capacitor, 0402 Pkg.
C3	100 pF Capacitor, 0402 Pkg.
C4	1000 pF Capacitor, 0603 Pkg.
C5	2.2 μ F Capacitor, Tantalum
R1	Resistor, 1210 Pkg.
L1	Inductor, 0603 Pkg.
U1	HMC474MP86 / HMC474MP86E
PCB [2]	107087 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.